20V N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

$V_{(BR)DSS}$	$R_{DS(ON)}$ max	I_D max T_A = 25°C
20V	0.99Ω @ V_{GS} = 4.5V	760mA
	1.2Ω @ V_{GS} = 2.5V	700mA
	2.4Ω @ V_{GS} = 1.8V	500mA
	3.0Ω @ V_{GS} = 1.5V	350mA

Features and Benefits

- Low On-Resistance
- Very low Gate Threshold Voltage, 1.0V max
- Low Input Capacitance
- Fast Switching Speed
- Ultra-Small Surface Mount Package 1mm x 0.6mm
- Low Package Profile, 0.5mm Maximum Package height
- ESD Protected Gate
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 standards for High Reliability**

Description and Applications

This MOSFET has been designed to minimize the on-state resistance ($R_{DS(on)}$) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

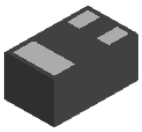
- General Purpose Interfacing Switch
- Power Management Functions
- Analog Switch

Mechanical Data

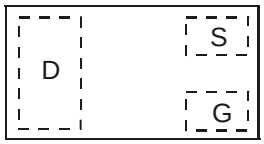
- Case: X1-DFN1006-3
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See diagram
- Terminals: Finish – NiPdAu over Copper leadframe. Solderable per MIL-STD-202, Method 208 e4
- Weight: 0.001 grams (approximate)

ESD PROTECTED

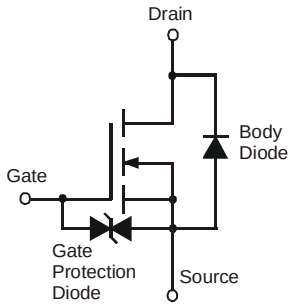
X1-DFN1006-3



Bottom View



Top View
Package Pin Configuration



Equivalent Circuit

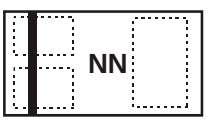
Ordering Information (Note 4)

Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DMN21D2UFB-7B	NN	7	8	10,000

Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at http://www.diodes.com.

Marking Information

DMN21D2UFB-7B



NN = Product Type Marking Code

Top View
Bar Denotes Gate and Source Side

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic			Symbol	Value	Units
Drain-Source Voltage			V_{DSS}	20	V
Gate-Source Voltage			V_{GSS}	±12	V
Continuous Drain Current (Note 6) V_{GS} = 4.5V	Steady State	T_A = 25°C T_A = 70°C	I_D	760 610	mA
	t<5s	T_A = 25°C T_A = 70°C	I_D	850 700	mA
Maximum Continuous Body Diode Forward Current (Note 6)			I_S	0.8	A
Pulsed Drain Current (Note 7)			I_{DM}	1.0	A

Thermal Characteristics @T_A = 25°C unless otherwise specified

Characteristic		Symbol	Value	Units
Total Power Dissipation (Note 4)	T_A = 25°C	P_D	0.38	W
	T_A = 70°C		0.25	
Thermal Resistance, Junction to Ambient (Note 4)	Steady State	$R_{\theta JA}$	325	°C/W
	t<5s		244	
Total Power Dissipation (Note 5)	T_A = 25°C	P_D	0.9	W
	T_A = 70°C		0.57	
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{\theta JA}$	141	°C/W
	t<5s		106	
Operating and Storage Temperature Range		T_J, T_{STG}	-55 to 150	°C

Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Drain-Source Breakdown Voltage	BV_{DSS}	20	-	-	V	V_{GS} = 0V, I_D = 250µA
Zero Gate Voltage Drain Current @T_c = 25°C	I_{DSS}	-	-	100	nA	V_{DS} = 20V, V_{GS} = 0V
Gate-Source Leakage	I_{GSS}	-	-	±1	µA	V_{GS} = ±10V, V_{DS} = 0V
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	$V_{GS(th)}$	0.4	-	1.0	V	V_{DS} = V_{GS}, I_D = 250µA
Static Drain-Source On-Resistance	$R_{DS\ (ON)}$	-	0.6	0.99	Ω	V_{GS} = 4.5V, I_D = 100mA
		-	0.7	1.2		V_{GS} = 2.5V, I_D = 50mA
		-	0.9	2.4		V_{GS} = 1.8V, I_D = 20mA
		-	1.2	3.0		V_{GS} = 1.5V, I_D = 10mA
Forward Transfer Admittance	$\|Y_{fs}\|$	180	-	-	mS	V_{DS} = 10V, I_D = 400mA
Diode Forward Voltage	V_{SD}	-	0.6	1.0	V	V_{GS} = 0V, I_S = 150mA
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	C_{iss}	-	27.6	-	pF	V_{DS} = 16V, V_{GS} = 0V, f = 1.0MHz
Output Capacitance	C_{oss}	-	4.0	-	pF	
Reverse Transfer Capacitance	C_{rss}	-	2.8	-	pF	
Total Gate Charge V_{GS} = 4.5V	Q_g	-	0.41	-	nC	V_{DS} = 10V, I_D = 250mA
Total Gate Charge V_{GS} = 10V	Q_g	-	0.93	-	nC	
Gate-Source Charge	Q_{gs}	-	0.06	-	nC	
Gate-Drain Charge	Q_{gd}	-	0.06	-	nC	
Turn-On Delay Time	$t_{D(on)}$	-	3.5	-	ns	V_{DD} = 10V, V_{GS} = 4.5V, R_L = 47Ω, R_G = 10Ω, I_D = 200mA
Turn-On Rise Time	t_r	-	4.2	-	ns	
Turn-Off Delay Time	$t_{D(off)}$	-	19.6	-	ns	
Turn-Off Fall Time	t_f	-	9.8	-	ns	

Notes:
5. Device mounted on FR-4 PCB, with minimum recommended pad layout.
6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal vias to bottom layer 1inch square copper plate
7. Device mounted on minimum recommended pad layout test board, 10µs pulse duty cycle = 1%.
8. Short duration pulse test used to minimize self-heating effect.
9. Guaranteed by design. Not subject to product testing.

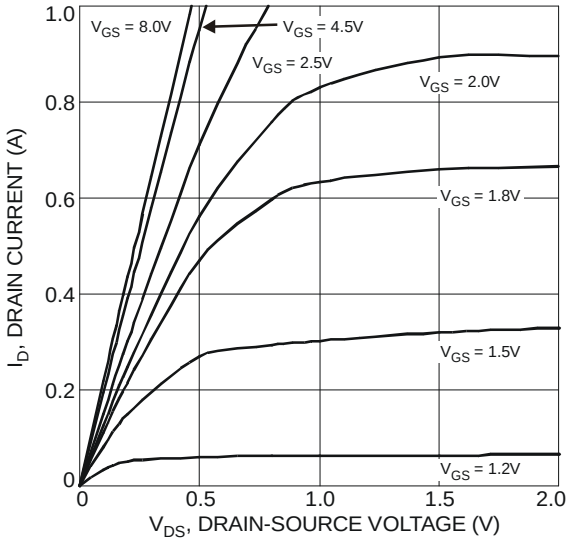


Fig. 1 Typical Output Characteristic

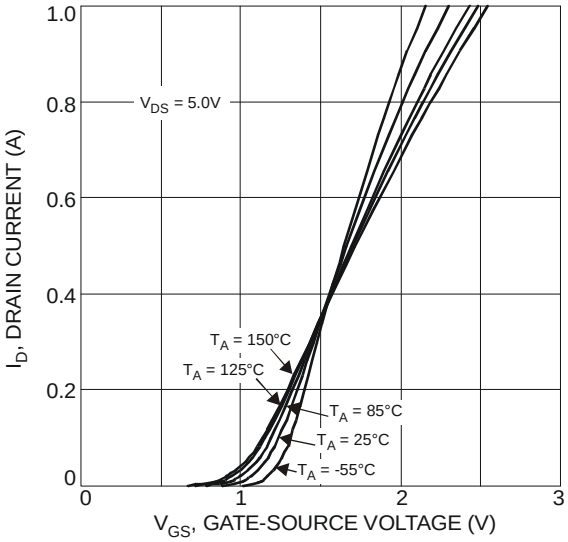


Fig. 2 Typical Transfer Characteristics

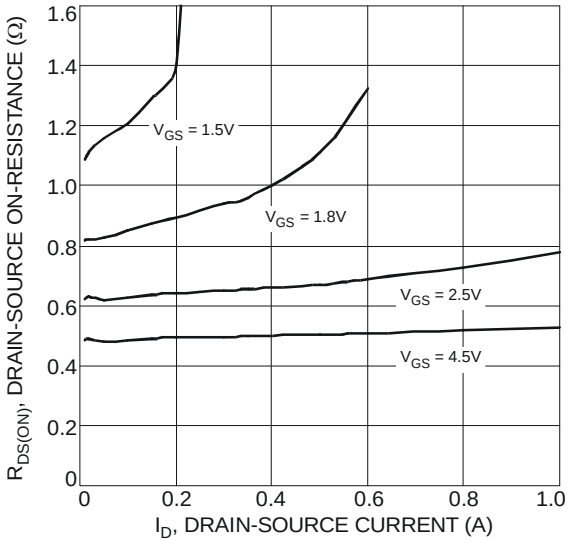


Fig. 3 Typical On-Resistance vs.
Drain Current and Gate Voltage

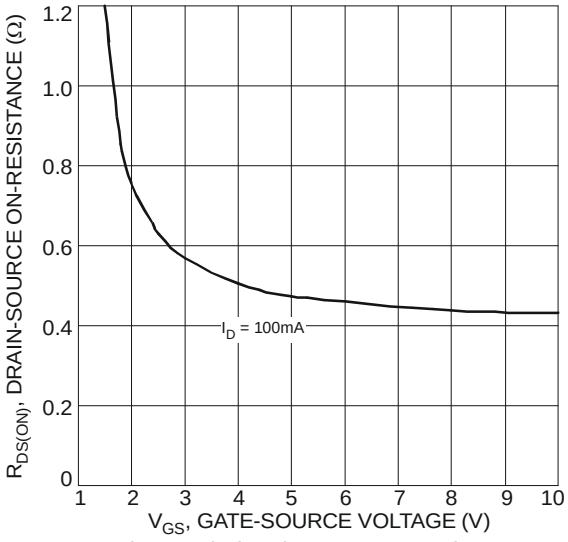


Fig. 4 Typical Drain-Source On-Resistance
vs. Gate-Source Voltage

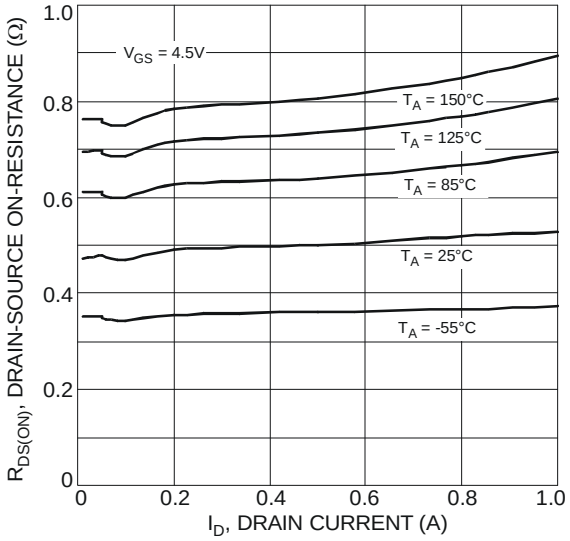


Fig. 5 Typical On-Resistance vs.
Drain Current and Temperature

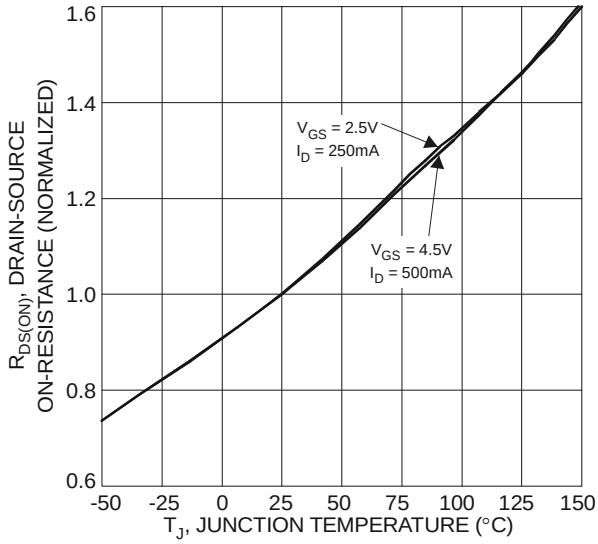


Fig. 6 On-Resistance Variation with Temperature

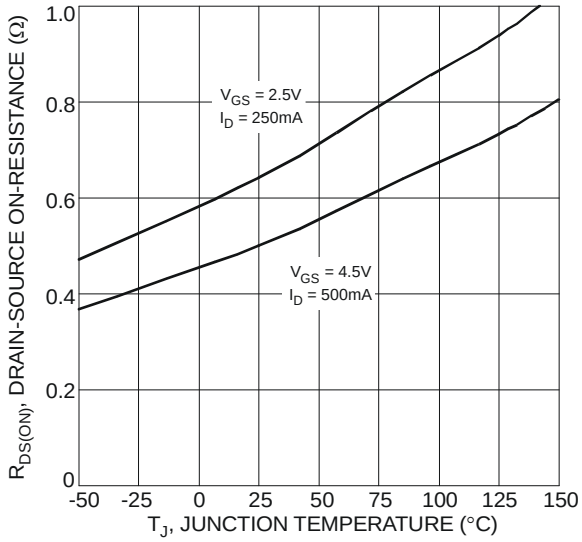


Fig. 7 On-Resistance Variation with Temperature

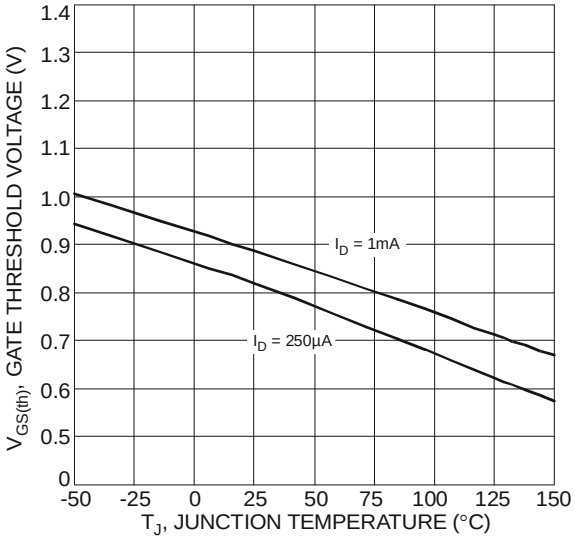


Fig. 8 Gate Threshold Variation vs. Ambient Temperature

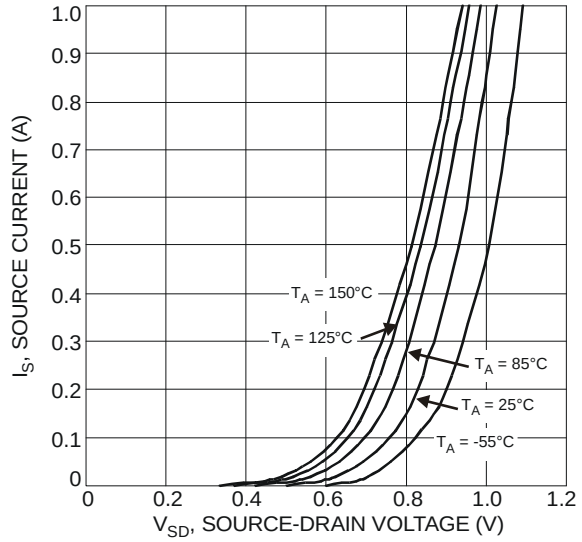


Fig. 9 Diode Forward Voltage vs. Current

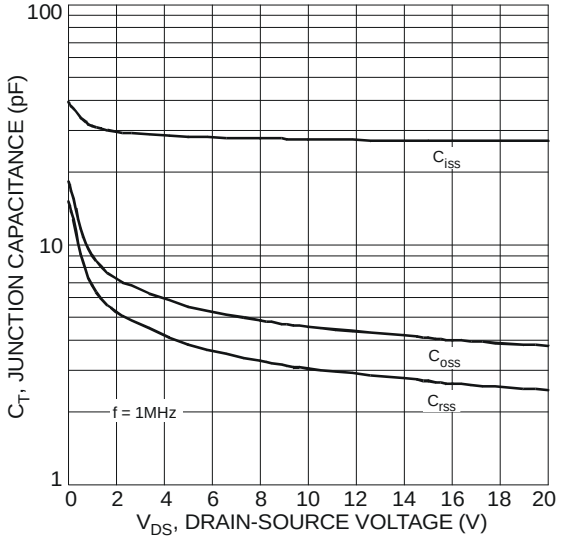


Fig. 10 Typical Junction Capacitance

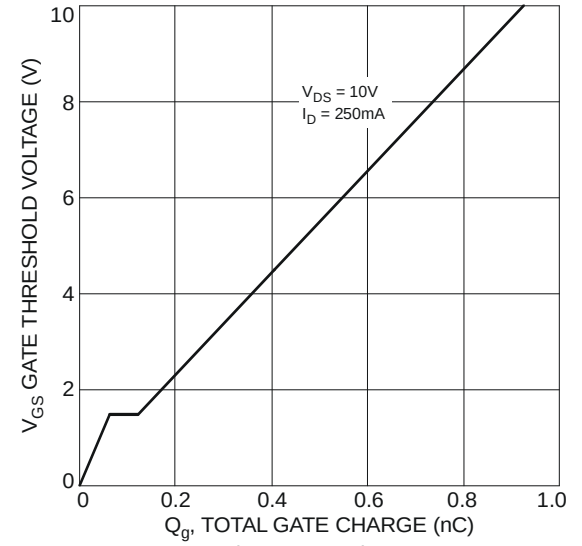


Fig. 11 Gate Charge

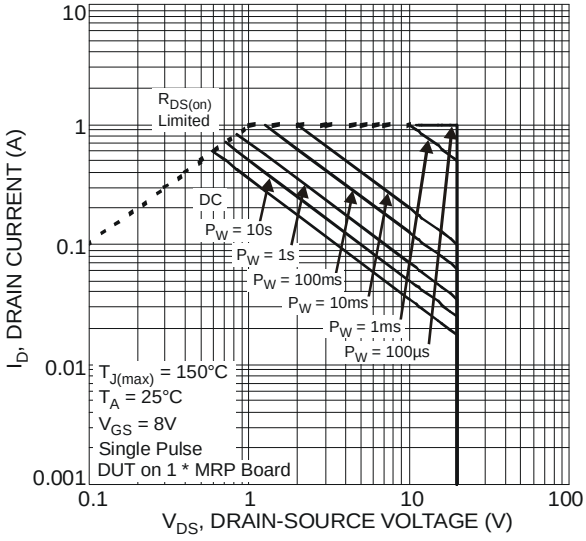


Fig. 12 SOA, Safe Operation Area

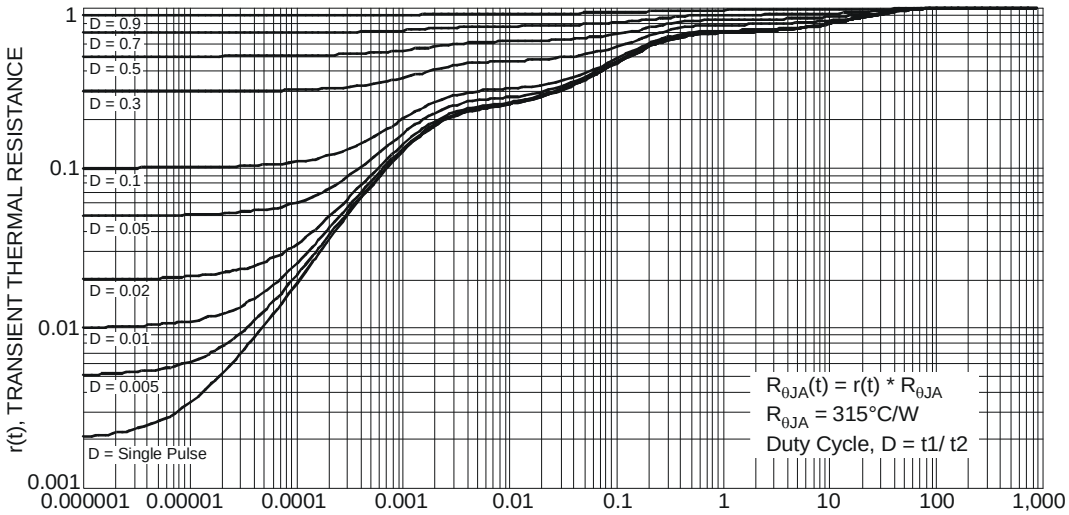
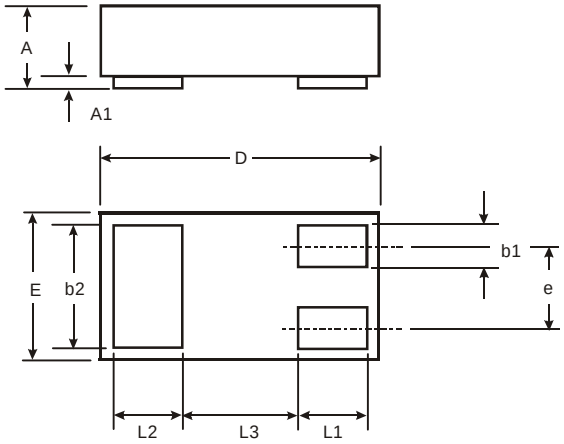


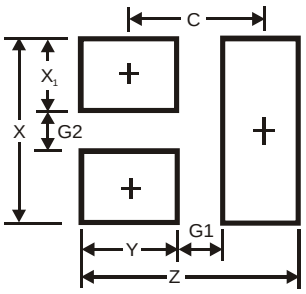
Fig. 13 Transient Thermal Resistance

Package Outline Dimensions



X1-DFN1006-3			
Dim	**Min**	**Max**	**Typ**
A	0.47	0.53	0.50
A1	0	0.05	0.03
b1	0.10	0.20	0.15
b2	0.45	0.55	0.50
D	0.95	1.075	1.00
E	0.55	0.675	0.60
e	—	—	0.35
L1	0.20	0.30	0.25
L2	0.20	0.30	0.25
L3	—	—	0.40
All Dimensions in mm			

Suggested Pad Layout



Dimensions	Value (in mm)
Z	1.1
G1	0.3
G2	0.2
X	0.7
X1	0.25
Y	0.4
C	0.7

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- Консультации по применению компонента;
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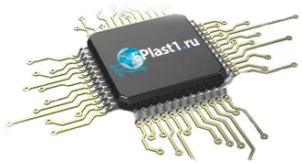
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



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